FFPF10F150S

10 A, 1500 V, Damper Diode

Features

- High Speed Recovery $t_{RR} = 170 \text{ ns } (@ I_F = 1 \text{ A})$
- Max Forward Voltage, $V_F = 1.6 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- 1500 V Reverse Voltage and High Reliability
- Low Forward Voltage
- This Device is Pb-Free and is RoHS Compliant

Applications

• Suitable for Damper Diode in Horizontal Deflection Circuits

ABSOLUTE MAXIMUM RATINGS

 $T_C = 25^{\circ}C$ unless otherwise noted

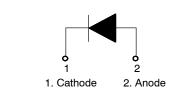
| Symbol | Parameter | Rating | Unit | |
|----------|---|--------------------|------|--|
| VRRM | Peak Repetitive Reverse Voltage | 1500 | V | |
| VRWM | Working Peak Reverse Voltage | V | | |
| IF(AV) | Average Rectified Forward Current @ $T_C = 125^{\circ}C$ | Forward Current 10 | | |
| IFSM | Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave | 100 | Α | |
| ТJ, Tsтg | Operating Junction and Storage Temperature | - 65 to +175 | °C | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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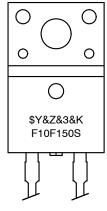
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TO-220, 2-Lead CASE 221AS

MARKING DIAGRAM



\$Y = ON Semiconductor Logo &Z&3 = Data Code (Year & Week)

&K = Lot

F10F150S = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFPF10F150S

THERMAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Max. | Unit |
|--------|--|------|------|
| Rejc | Maximum Thermal Resistance, Junction to Case | 3.0 | °C/W |

PACKAGE MARKING AND ORDERING INFORMATION

| Part Number | Top Mark | Package | Packing Method | Reel Size | Tape Width | Quantity |
|---------------|----------|------------|----------------|-----------|------------|----------|
| FFPF10F150STU | F10F150S | TO-220F-2L | Tube | N/A | N/A | 30 |

ELECTRICAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

| Parameter | Conditions | | Min. | Тур. | Max. | Unit |
|----------------------------|---|---|--------|--------|------------|------|
| V _F (Note 1) | Maximum Instantaneous Forward Voltage I _F = 10 A I _F = 10 A | T _C = 25°C T _C = 125°C | _ _ | - - | 1.6 1.4 | ٧ |
| I _R (Note 1) | Maximum Instantaneous Reverse Current @ rated V _R | T _C = 25°C T _C = 125°C | - - | - - | 10 80 | μΑ |
| t _{RR} | Maximum Reverse Recovery Time ($I_F = 1 \text{ A}, di_F/dt = 50 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$) | | _ | _ | 170 | ns |
| t _{FR} | Maximum Forward Recovery Time (I _F = 6.5 A, di_F/dt = 50 A/ μ s) | | _ | _ | 250 | ns |
| V_{FRM} | Maximum Forward Recovery Voltage | | - | - | 14 | V |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Test Circuit and Waveforms

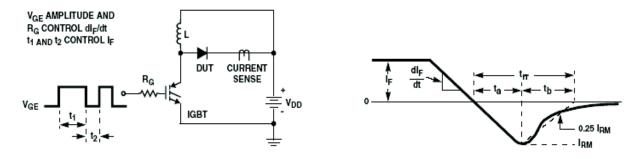


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

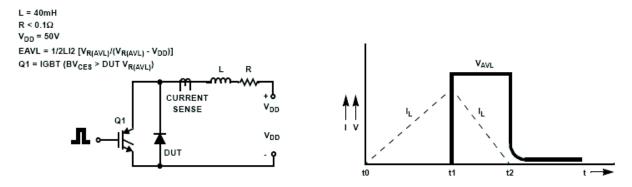
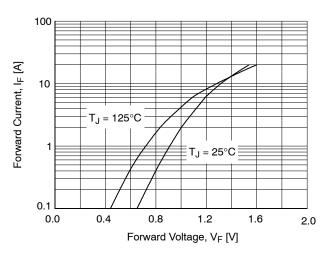


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

^{1.} Pulse: Test Pulse Width = 300 μs, Duty Cycle = 2%

FFPF10F150S

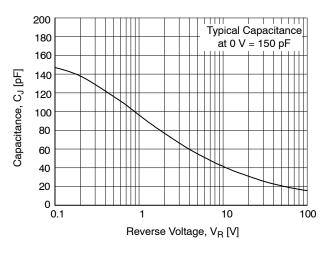
TYPICAL CHARACTERISTICS



100 10 Reverse Current, IR [µA] T_J = 125°C $T_J = 100^{\circ}C$ 0.1 T_J = 25°C 0.01 0.001 0 300 600 900 1200 1500 Reverse Voltage, V_R [V]

Figure 3. Typical Forward Voltage Drop

Figure 4. Typical Reverse Current



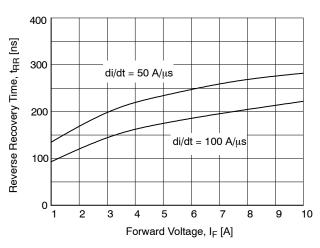
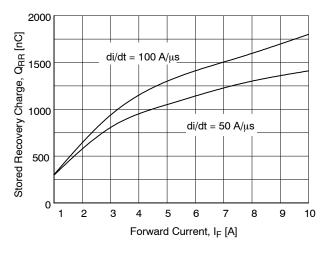


Figure 5. Typical Junction Capacitance

Figure 6. Typical Reverse Recovery Time



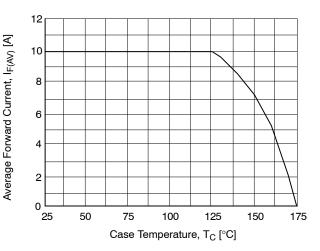
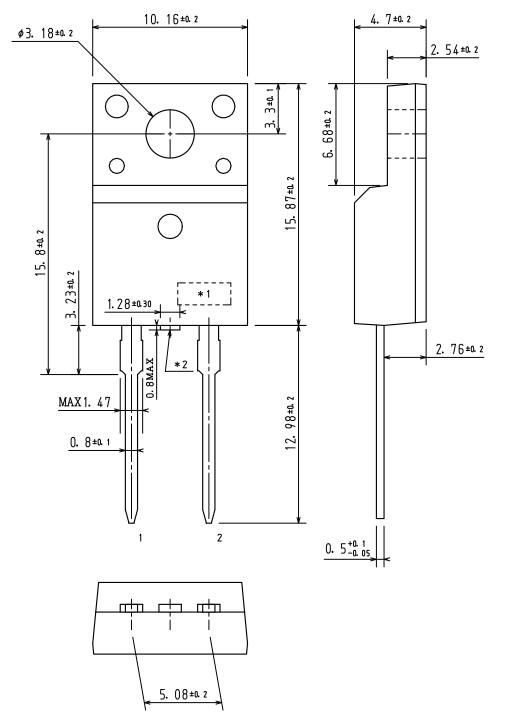


Figure 7. Typical Stored Charge

Figure 8. Forward Current Deration Curve

TO-220 Fullpack, 2-Lead / TO-220F-2FS CASE 221AS ISSUE O

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